

#### **Description**

The US03236D is an ultra low capacitance TVS array,utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The US03236D has an ultra-low capacitance with a typical value at 0.3pF (I/O to I/O) ,and complies with the IEC 61000-4-2 (ESD) standard with ±25kV air and ±20kV contact discharge. It is assembled into a 6-pin lead-free SOT23-6 package. The low capacitance array make it ideal for four high speed data and transmission line. This device is optimized for ESD protection of portable electronics.

### **Mechanical Characteristics**

Package: SOT23-6Lead Finish: Matte Tin

Case Material: "Green" Molding Compound
 Moisture Sensitivity: Level 3 per J-STD-020
 Terminal Connections: See Diagram Below

Marking Information: See Below

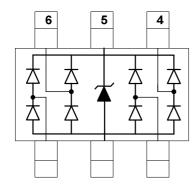
#### **Features**

- ◆ Ultra low capacitance: 0.3pF typical (I/O to I/O)
- ◆ Ultra low leakage: nA level
- ♦ Ultra low operating voltage: 3.3V
- Low clamping voltage
- ◆ Up to 4 data lines and one power line protects
- ♦ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
     Air discharge: ±25kV
     Contact discharge: ±20kV
  - IEC61000-4-5 (Lightning) : 5A(8/20μs)
- ♦ RoHS Compliant

### **Applications**

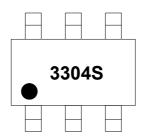
- ◆ LAN Applications
- ◆ Fingerprint
- Video Lines Protection
- ♦ Handheld Electronics
- ◆ 3.3V Operating Systems
- Analog Input Lines Protection
- ◆ Data and I/O Lines Protection

## **Dimensions and Pin Configuration**



Circuit and Pin Schematic

## **Marking Information**



3304S = Device Marking Code
Dot denotes Pin1

## **Ordering Information**

Part Number	Marking	Packaging	Reel Size
US03236D	3304S	3000/Tape & Reel	7 inch

## Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

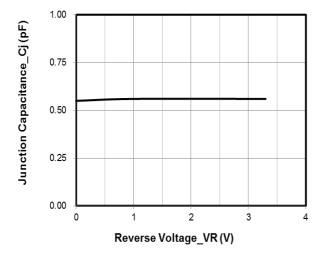
Parameter	Symbol	Value	Unit
Peak Pulse Power(tp=8/20µs)	Ррр	100	W
Peak Pulse Current (tp=8/20µs)	IPP	5	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	±25 ±20	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +125	°C

## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

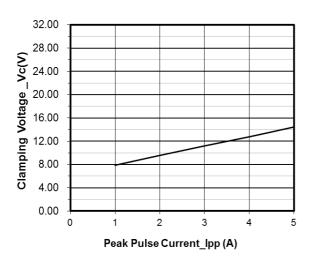
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			3.3	V	Any I/O pin to ground
Breakdown Voltage	VPT	3.5			V	IT = 2μA, any I/O pin to ground
Snap-Back Voltage	VsB	2.8			V	IT = 50mA, any I/O pin to ground
Reverse Leakage Current	I <sub>R</sub>			0.2	μA	VRWM = 3.3V, any I/O pin to ground
Clamping Voltage	Vc			10	V	IPP = 1A (8 x 20µs pulse), any I/O pin to ground
Clamping Voltage	Vc			20	V	IPP = 5A (8 x 20µs pulse), any I/O pin to ground
Junction Capacitance	Cl		0.3	0.4	pF	VR = 0V, f = 1MHz, between I/O pins
Junction Capacitance	CJ		0.6	0.8	pF	VR = 0V, f = 1MHz, any I/O pin to ground

Note 1: I/O pins are Pin 1, 3, 4 and 6

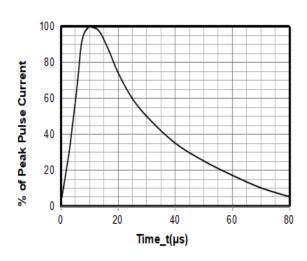
## Typical Performance Characteristics (TA=25°C unless otherwise Specified)



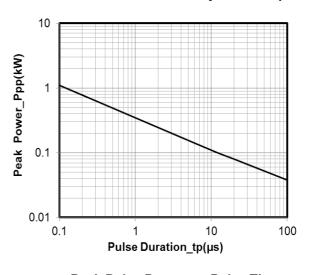
Junction Capacitance vs. Reverse Voltage



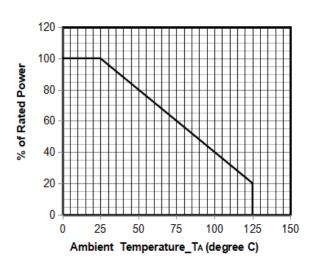
Clamping Voltage vs. Peak Pulse Current



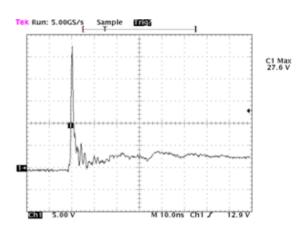
8 X 20µs Pulse Waveform



Peak Pulse Power vs. Pulse Time



**Power Derating Curve** 



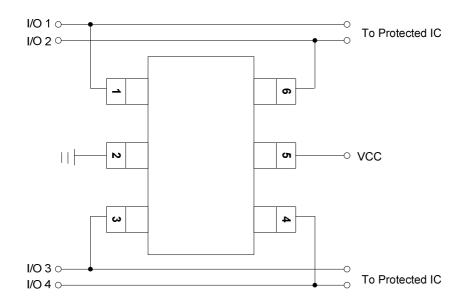
Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

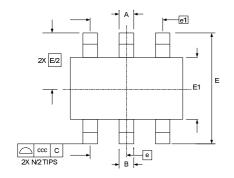
8 kV Contact per IEC61000-4-2

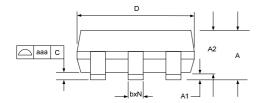
### **Typical Application**

The US03236D is designed to protect four data lines from transient over-voltages by clamping them to fixed reference. When the voltage on the protected line exceeds the reference voltage (plus diode VF) the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. Data lines are connected at pins 1, 3, 4 and 6. The negative reference (REF1) is connected at pin 2. This pin should be connected directly to a ground plane on the board for best results. The path length is kept as short as possible to minimize parasitic inductance. The positive reference (REF2) is connected at pin 5.



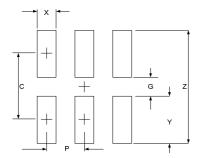
# **SOT23-6 Package Outline Drawing**





	DIMENSIONS					
	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90		1.45	0.035		0.057
A1	0.00		0.15	0.000		0.006
A2	0.90	1.15	1.30	0.035	0.045	0.051
В	0.25		0.50	0.010		0.020
С	0.08		0.22	0.003		0.009
D	2.80	2.90	3.10	0.110	0.114	0.122
E1	1.50	1.60	1.75	0.060	0.063	0.069
Е	2.80 BSC			0.110 BSC		
е	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
Ν	6			6		
aaa	0.10			0.004		
ccc	0.20				0.008	•

# **Suggested Land Pattern**



SYM	DIMENSIONS			
	MILLIMETERS	INCHES		
С	2.50	0.098		
G	1.40	0.055		
Р	0.95	0.037		
Х	0.60	0.024		
Y	1.10	0.043		
Z	3.60	0.141		